Silicon Epitaxial Planar Switching Diode

Applications

· Ultra high speed switching





SOT-323 Plastic Package Marking Code: **A7**

Absolute Maximum Ratings ($T_a = 25$ °C)

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V_{RM}	20	V
Reverse Voltage	V _R	20	V
Average Rectified Forward Current	I _{F(AV)}	100	mA
Maximum (Peak) Forward Current (Single)	I _{FM}	200	mA
Non-repetitive Peak Forward Surge Current (t = 1 µs)	I _{FSM}	4	A
Power Dissipation	P _d	200	mW
Junction Temperature	T _j	150	°C
Storage Temperature Range	T _{stg}	- 55 to + 150	°C

Characteristics at T_a = 25 °C

Parameter	Symbol	Max.	Unit
Forward Voltage at I _F = 10 mA	V _F	WWW.D	720.0
Reverse Current at V _R = 15 V	I _R	0.1	μΑ
Capacitance between Terminals at V _R = 6 V, f = 1 MHz	Ст	4	pF



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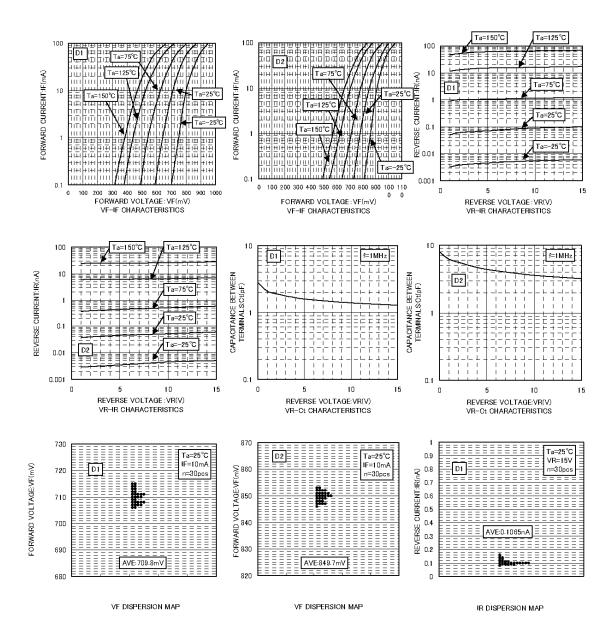








Dated: 15/06/2009





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